

## COMPLEMENTARY SILICON POWER TRANSISTORS

- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES

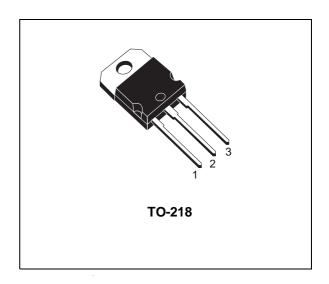
#### **APPLICATIONS**

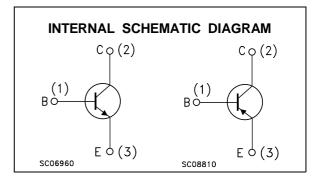
■ GENERAL PURPOSE SWITCHING

#### **DESCRIPTION**

The TIP33C is a silicon Epitaxial-Base NPN power transistor mounted in TO-218 plastic package. It is intented for use in linear and switching applications.

The complementary PNP type is TIP34C.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
		NPN	TIP33C	
		PNP	TIP34C	
$V_{CBO}$	Collector-Base Voltage (I <sub>E</sub> = 0)		140	V
$V_{CES}$	Collector-Emitter Voltage (V <sub>BE</sub> = 0)		140	V
$V_{CEO}$	Collector-Emitter Voltage (I <sub>B</sub> = 0)		100	V
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)		7	V
Ic	Collector Current		10	А
I <sub>CM</sub>	Collector Peak Current		12	А
Ι <sub>Β</sub>	Base Current		3	А
$P_{tot}$	Total Dissipation at T <sub>c</sub> ≤ 25 °C		80	W
T <sub>stg</sub>	Storage Temperature		-65 to 150	°C
Tj	Max. Operating Junction Temperature		150	°C

For PNP types voltage and current values are negative.

October 1999 1/4

#### THERMAL DATA

R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	1.56	°C/W	
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### **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{o}C$ unless otherwise specified)

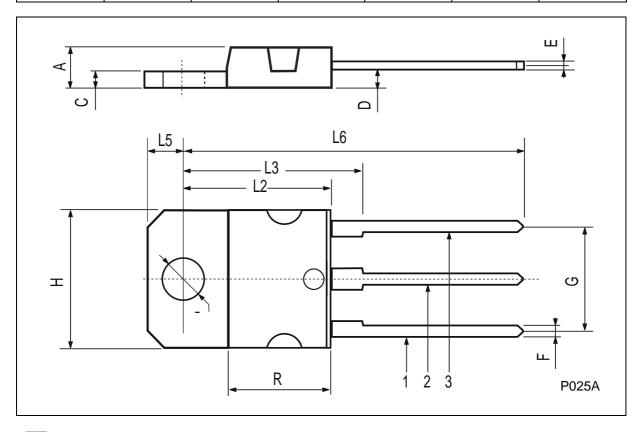
Symbol	Parameter	Test	Conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector Cut-off Current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 140 V				400	μΑ
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	V <sub>CE</sub> = 60 V				0.7	mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V				1	mA
V <sub>CEO(sus)*</sub>	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 30 mA		100			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3 A I <sub>C</sub> = 10 A	$I_B = 0.3 A$ $I_B = 2.5 A$			1 4	V V
V <sub>BE(on)</sub> *	Base-Emitter Voltage	I <sub>C</sub> = 3 A I <sub>C</sub> = 10 A	$V_{CE} = 4 V$ $V_{CE} = 4 V$			1.6 3	V V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 1 A I <sub>C</sub> = 3 A	V <sub>CE</sub> = 4 V V <sub>CE</sub> = 4 V	40 20		100	
h <sub>fe</sub>	Small Signal Current Gain	I <sub>C</sub> = 0.5 A f = 1 KHz	V <sub>CE</sub> = 10 V	20			
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = 0.5 A f = 1 MHz	V <sub>CE</sub> = 10 V	3			MHz
t <sub>on</sub> t <sub>s</sub> t <sub>f</sub>	RESISTIVE LOAD Turn-on Time Storage Time Fall Time	$VCC = 30V$ $V_{BB} = -6 V$ $t_p = 20 \mu s$	$I_C = 6 A$ $I_{B1} = -I_{B2} = 0.6 A$		0.6 0.4 1		μs μs μs

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

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# TO-218 (SOT-93) MECHANICAL DATA

DIM.		mm			inch	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	4.7		4.9	0.185		0.193
С	1.17		1.37	0.046		0.054
D		2.5			0.098	
Е	0.5		0.78	0.019		0.030
F	1.1		1.3	0.043		0.051
G	10.8		11.1	0.425		0.437
Н	14.7		15.2	0.578		0.598
L2	_		16.2	-		0.637
L3		18			0.708	
L5	3.95		4.15	0.155		0.163
L6		31			1.220	
R	_		12.2	-		0.480
Ø	4		4.1	0.157		0.161



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